

Data Sheet

ADP196

FEATURES

- Low R_{DSON}: 10 mΩ (WLCSP) or 27 mΩ (LFCSP)**
- Wide input voltage range: 1.8 V to 5.5 V**
- Quick output discharge (QOD) circuit (ADP196-01)**
- 3 A continuous operating current to 70°C**
- 1.2 V logic-compatible enable input**
- Low 25 μA quiescent current, V_{IN} = 1.8 V**
- Low 40 μA quiescent current, V_{IN} = 5.5 V**
- Overttemperature and overcurrent protection**
- Ultralow shutdown current: <1 μA**
- Ultrasmall 1.0 mm × 1.5 mm, 0.5 mm pitch, 6-ball WLCSP**
- Tiny 2.0 mm × 2.0 mm × 0.55 mm, 0.65 mm pitch, 6-lead LFCSP**

APPLICATIONS

- Mobile phones**
- Digital cameras and audio devices**
- Portable and battery-powered equipment**

GENERAL DESCRIPTION

The ADP196 is a high-side load switch designed for operation from 1.8 V to 5.5 V. This load switch provides power domain isolation, helping to extend battery operation. The device contains a low on-resistance, N-channel MOSFET that supports more than 3 A of continuous current and minimizes power loss. In addition, R_{DSON} is constant, independent of the V_{IN} voltage. The low 25 μA quiescent current and ultralow shutdown current make the ADP196 ideal for battery-powered portable equipment. The built-in level shifter for enable logic makes the ADP196 compatible with many processors and GPIO controllers.

Overttemperature protection circuitry is activated if the junction temperature exceeds 125°C, thereby protecting the ADP196 and downstream circuits from potential damage. Overcurrent protection is provided in the form of constant current limiting.

TYPICAL APPLICATION CIRCUIT

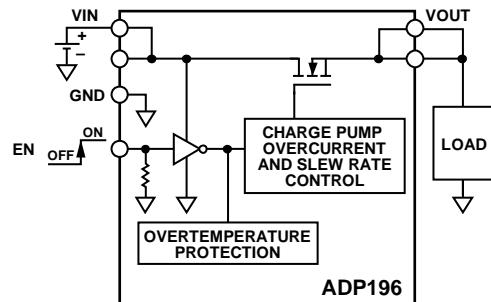


Figure 1.

The ADP196-01 incorporates an internal quick output discharge circuit to discharge the output capacitance when the ADP196-01 output is disabled.

The ADP196 in the WLCSP package occupies minimal printed circuit board (PCB) area with a footprint of less than 1.5 mm² and a height of 0.60 mm.

The ADP196 is available in an ultrasmall, 1.0 mm × 1.5 mm, 0.5 mm pitch, 6-ball WLCSP and a 2.0 mm × 2.0 mm × 0.55 mm, 0.65 mm pitch, 6-lead LFCSP.

Rev. 0

Document Feedback

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700 ©2013 Analog Devices, Inc. All rights reserved.
Technical Support www.analog.com

TABLE OF CONTENTS

| | | | |
|--|---|--|----|
| Features | 1 | Typical Performance Characteristics | 6 |
| Applications..... | 1 | Theory of Operation | 9 |
| Typical Application Circuit | 1 | Applications Information | 10 |
| General Description | 1 | Capacitor Selection | 10 |
| Revision History | 2 | Ground Current..... | 10 |
| Specifications..... | 3 | Enable Feature | 10 |
| Timing Diagram | 3 | Timing..... | 11 |
| Absolute Maximum Ratings..... | 4 | Current-Limit and Thermal Overload Protection..... | 11 |
| Thermal Resistance | 4 | Outline Dimensions | 12 |
| ESD Caution..... | 4 | Ordering Guide | 12 |
| Pin Configurations and Function Descriptions | 5 | | |

REVISION HISTORY

3/13—Revision 0: Initial Version

SPECIFICATIONS

$V_{IN} = 1.8 \text{ V}$, $V_{EN} = V_{IN}$, $I_{OUT} = 1 \text{ A}$, $T_A = 25^\circ\text{C}$, $T_J = -40^\circ\text{C}$ to $+85^\circ\text{C}$ for minimum/maximum specifications, unless otherwise noted.

Table 1.

| Parameter | Symbol | Test Conditions/Comments | Min | Typ | Max | Unit |
|--|----------------|---|-------|-------|-----|------------------|
| INPUT VOLTAGE RANGE | V_{IN} | $T_J = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | 1.8 | | 5.5 | V |
| EN INPUT | | | | | | |
| EN Input Logic High | V_{IH} | $V_{IN} = 1.8 \text{ V}$ to 5.5 V | 1.2 | | | V |
| EN Input Logic Low | V_{IL} | $V_{IN} = 1.8 \text{ V}$ to 5.5 V | | 0.4 | | V |
| EN Input Pull-Down Current | I_{EN} | $V_{IN} = 1.8 \text{ V}$ | | 500 | | nA |
| CURRENT | | | | | | |
| Ground Current | I_{GND} | $V_{IN} = 1.8 \text{ V}$ $V_{IN} = 3.4 \text{ V}$ $V_{IN} = 4.2 \text{ V}$ $V_{IN} = 5.5 \text{ V}$ | 25 | | | μA |
| Shutdown Current | I_{OFF} | $V_{EN} = \text{GND}$, $V_{OUT} = 0 \text{ V}$, $V_{IN} = 4.2 \text{ V}$ $V_{EN} = \text{GND}$, $V_{OUT} = 0 \text{ V}$, $V_{IN} = 1.8 \text{ V}$ to 5.5 V | 30 | 40 | 40 | μA |
| Continuous Operating Current ¹ | I_{OUT} | $V_{IN} = 1.8 \text{ V}$ to 5.5 V | 40 | | | μA |
| VIN TO VOUT ON RESISTANCE | R_{DSON} | | 3 | | | A |
| WLCSP | | $V_{IN} = 5.5 \text{ V}$ $V_{IN} = 4.2 \text{ V}$ $V_{IN} = 1.8 \text{ V}$ | 0.01 | | | Ω |
| LFCSP | | $V_{IN} = 5.5 \text{ V}$ $V_{IN} = 4.2 \text{ V}$ $V_{IN} = 1.8 \text{ V}$ | 0.01 | 0.015 | | Ω |
| VOUT TURN-ON DELAY TIME | t_{ON_DLY} | See Figure 2 $V_{IN} = 1.8 \text{ V}$ to 5.5 V , $C_{LOAD} = 1 \mu\text{F}$ | 0.027 | | | ms |
| ACTIVE PULL-DOWN RESISTANCE (ADP196-01 OPTION ONLY) | $R_{PULLDOWN}$ | $V_{IN} = 3.2 \text{ V}$ | 370 | | | Ω |
| CURRENT-LIMIT THRESHOLD | I_{LIM} | $V_{IN} = 1.8 \text{ V}$ to 5.5 V , $C_{LOAD} = 1 \mu\text{F}$ | 3.1 | 4 | | A |
| THERMAL SHUTDOWN | | | | | | |
| Thermal Shutdown Threshold | TS_{SD} | T_J rising | 125 | | | $^\circ\text{C}$ |
| Thermal Shutdown Hysteresis | TS_{SD-HYS} | | 15 | | | $^\circ\text{C}$ |

¹ At an ambient temperature of 85°C , the part can withstand a continuous current of 2.22 A. At a load current of 3 A, the operational lifetime derates to 2190 hours.

TIMING DIAGRAM

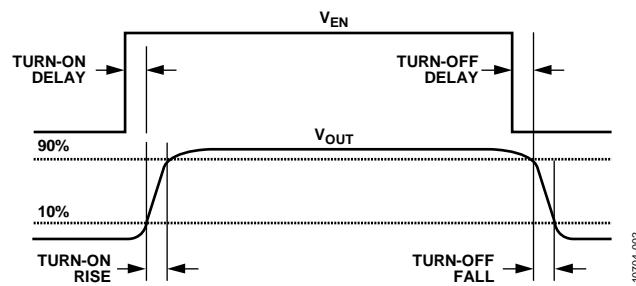


Figure 2. Timing Diagram

ABSOLUTE MAXIMUM RATINGS

Table 2.

| Parameter | Rating |
|--|----------------------|
| VIN to GND | –0.3 V to +6.5 V |
| VOUT to GND | –0.3 V to V_{IN} |
| EN to GND | –0.3 V to +6.5 V |
| Continuous Drain Current $T_A = 25^\circ\text{C}$ | $\pm 4 \text{ A}$ |
| $T_A = 85^\circ\text{C}$ | $\pm 2.22 \text{ A}$ |
| Continuous Diode Current | –50 mA |
| Storage Temperature Range | –65°C to +150°C |
| Operating Junction Temperature Range | –40°C to +105°C |
| Soldering Conditions | JEDEC J-STD-020 |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

Table 3. Typical θ_{JA} and Ψ_{JB} Values

| Package Type | θ_{JA} | Ψ_{JB} | Unit |
|--------------|---------------|-------------|------|
| 6-Ball WLCSP | 260 | 58 | °C/W |
| 6-Lead LFCSP | 68.9 | 44.1 | °C/W |

ESD CAUTION



ESD (electrostatic discharge) sensitive device.
Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

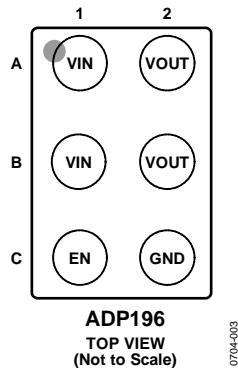


Figure 3. 6-Ball WLCSP Pin Configuration

Table 4. 6-Ball WLCSP Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|---------|----------|--|
| A1, B1 | VIN | Input Voltage. |
| A2, B2 | VOUT | Output Voltage. |
| C1 | EN | Enable Input. Drive EN high to turn on the switch, or drive EN low to turn off the switch. |
| C2 | GND | Ground. |

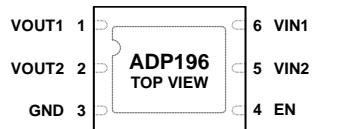


Figure 4. 6-Lead LFCSP Pin Configuration

Table 5. 6-Lead LFCSP Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|---------|----------|--|
| 1 | VOUT1 | Output Voltage. Connect VOUT1 and VOUT2 together. |
| 2 | VOUT2 | Output Voltage. Connect VOUT1 and VOUT2 together. |
| 3 | GND | Ground. |
| 4 | EN | Enable Input. Drive EN high to turn on the switch, or drive EN low to turn off the switch. |
| 5 | VIN2 | Input Voltage. Connect VIN1 and VIN2 together. |
| 6 | VIN1 | Input Voltage. Connect VIN1 and VIN2 together. |
| | EP | The exposed pad must be connected to ground. |

TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN} = 1.8 \text{ V}$, $V_{EN} = V_{IN}$, $C_{IN} = C_{OUT} = 1 \mu\text{F}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

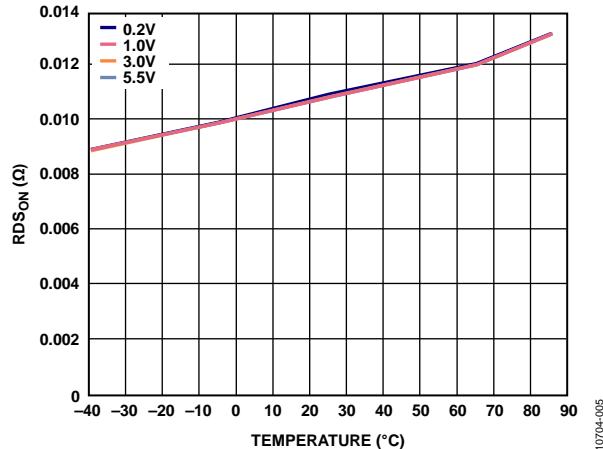


Figure 5. R_{DSON} vs. Temperature, $I_{OUT} = 50 \text{ mA}$, Different Input Voltages (V_{IN})

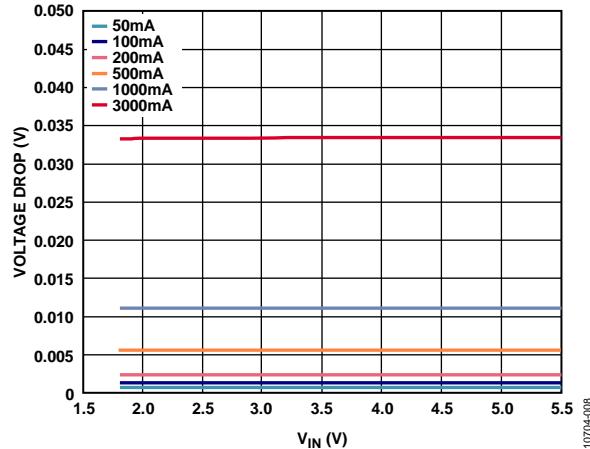


Figure 8. Voltage Drop vs. Input Voltage (V_{IN}), Different Load Currents

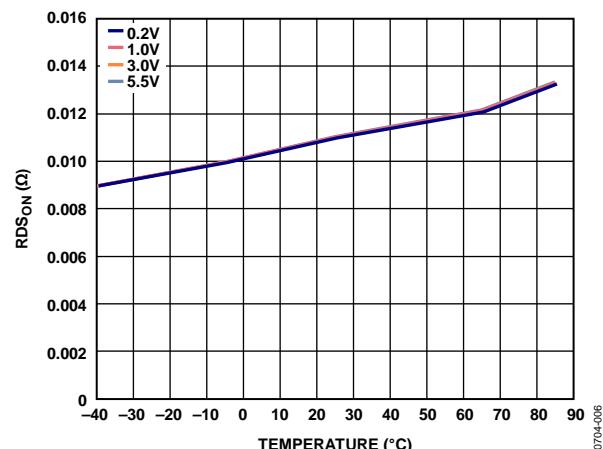


Figure 6. R_{DSON} vs. Temperature, $I_{OUT} = 3 \text{ A}$, Different Input Voltages (V_{IN})

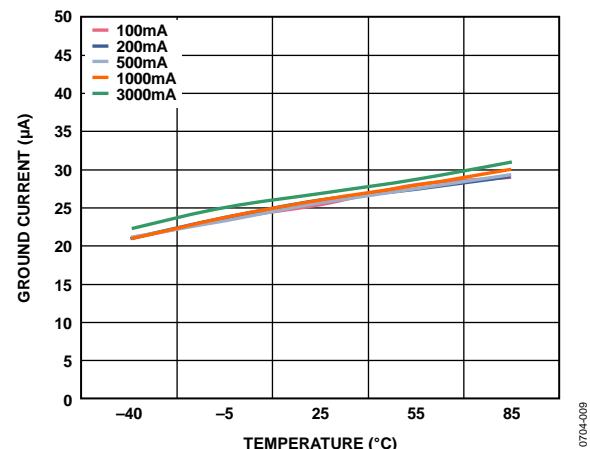


Figure 9. Ground Current vs. Temperature, Different Load Currents, $V_{IN} = 1.8 \text{ V}$

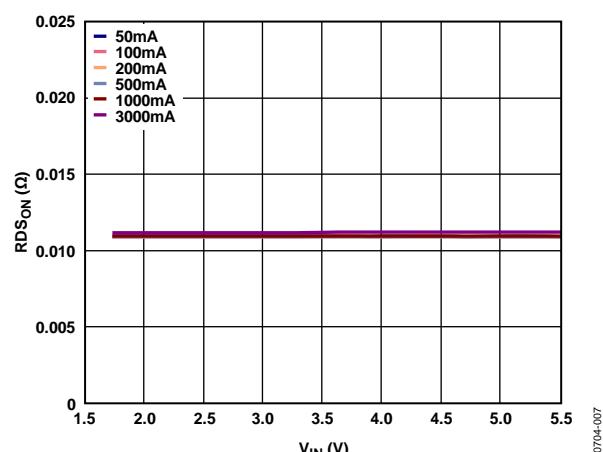


Figure 7. R_{DSON} vs. Input Voltage (V_{IN}), Different Load Currents

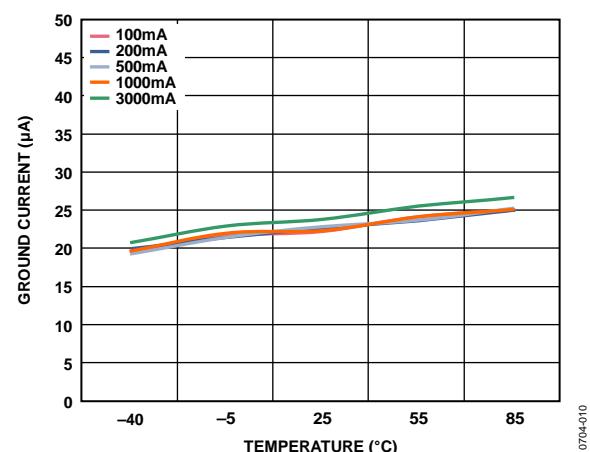
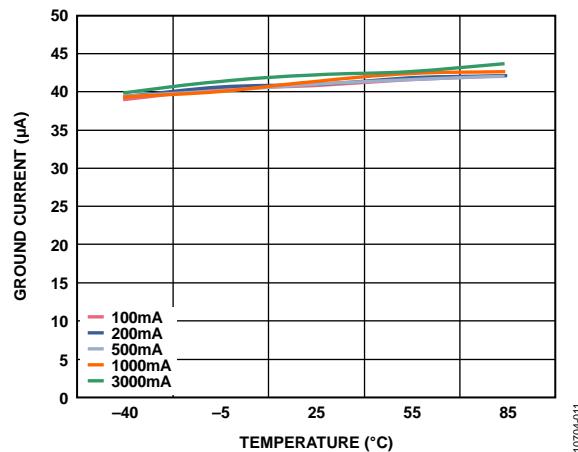
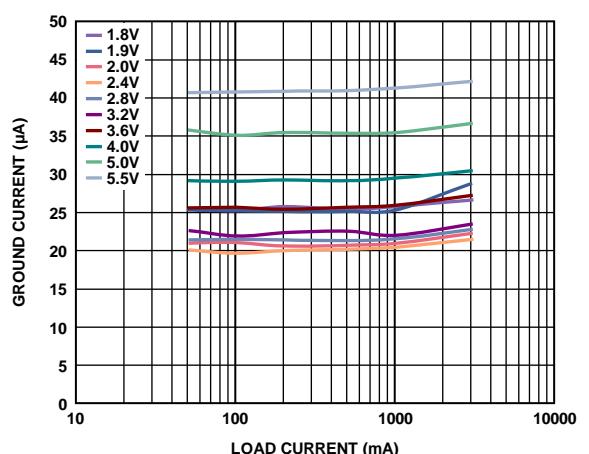


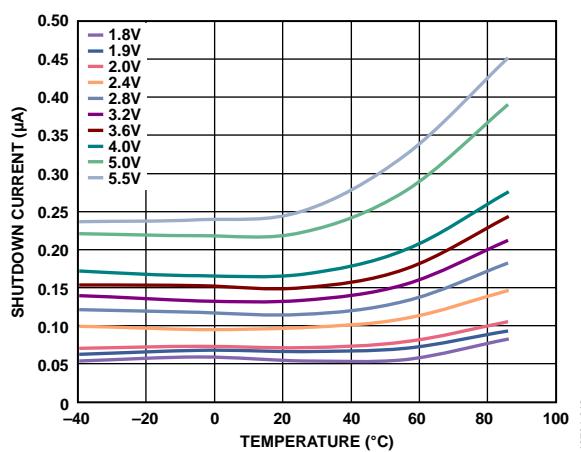
Figure 10. Ground Current vs. Temperature, Different Load Currents, $V_{IN} = 3.3 \text{ V}$



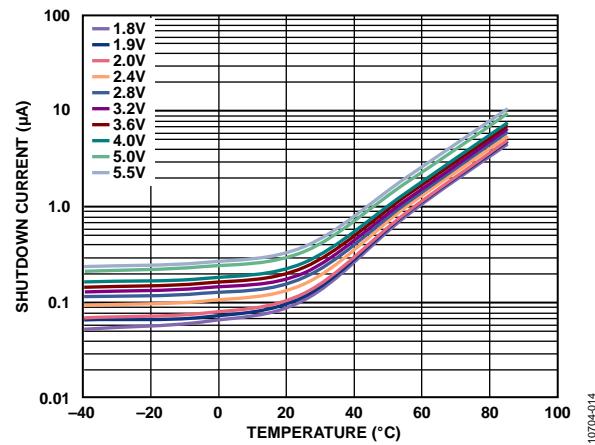
10704-011



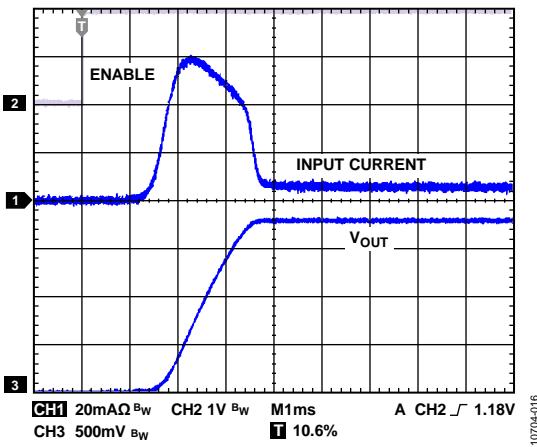
10704-012

Figure 12. Ground Current vs. Load Current, Different Input Voltages (V_{IN})

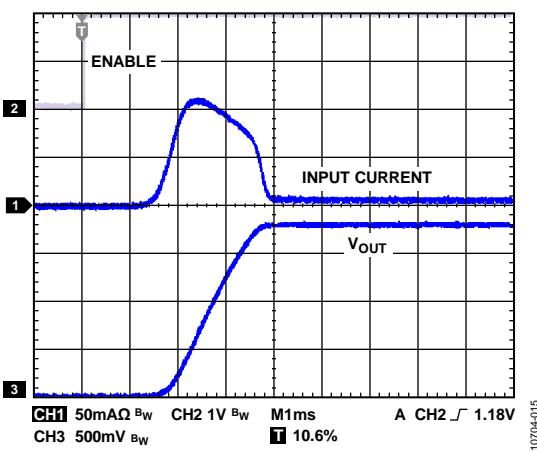
10704-013



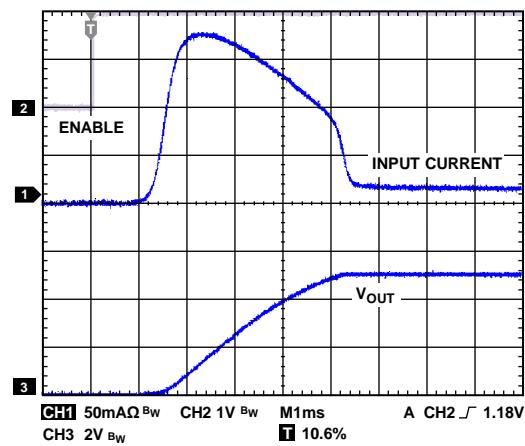
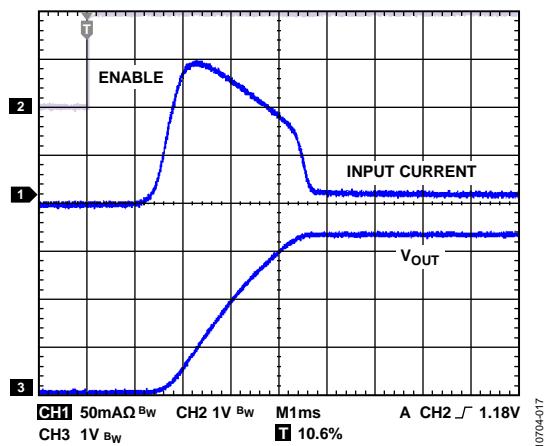
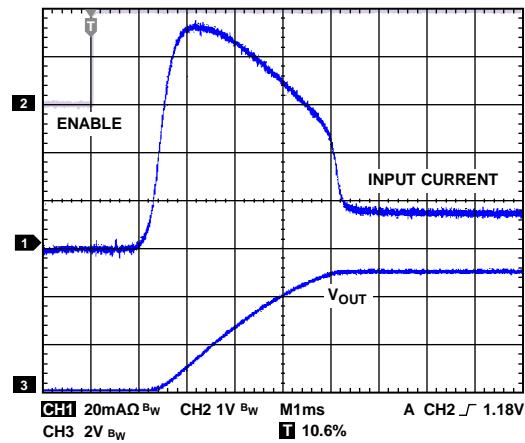
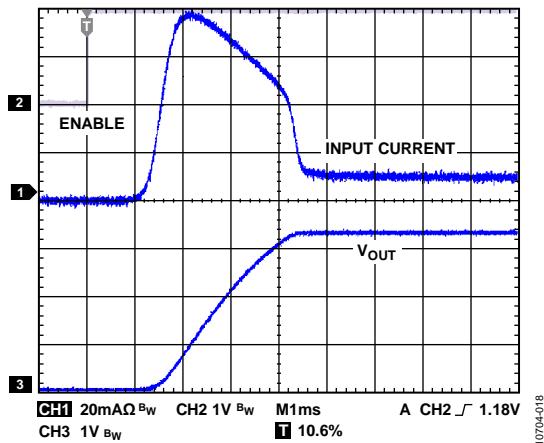
10704-014

Figure 14. Shutdown Current vs. Temperature, $V_{OUT} = 0\text{ V}$, Different Input Voltages (V_{IN})

10704-016

Figure 15. Typical Turn-On Time and Inrush Current, $V_{IN} = 1.8\text{ V}$, $C_{OUT} = 47\text{ }\mu\text{F}$, 330 Ω Load

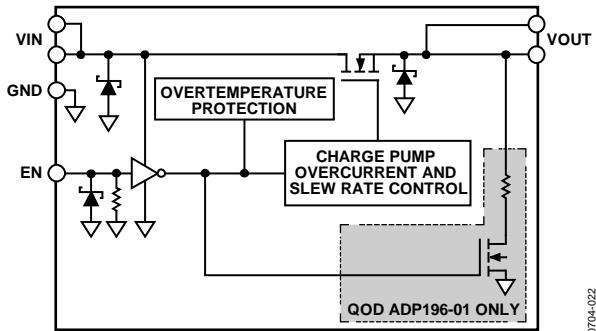
10704-015



THEORY OF OPERATION

The ADP196 is a high-side NMOS load switch controlled by an internal charge pump. The ADP196 is designed to operate with power supply voltages from 1.8 V to 5.5 V.

An internal charge pump biases the NMOS switch to achieve a relatively constant, ultralow on resistance of 10 mΩ across the entire input voltage range (6-ball WLCSP package). The use of the internal charge pump also allows for controlled turn-on times. Turning the NMOS switch on and off is controlled by the enable input, EN, which is capable of interfacing directly to 1.2 V logic signals.



The ADP196 supports 3 A of continuous current as long as T_j is less than 70°C. At 85°C, the rated current decreases to 2.22 A. Overcurrent protection limits the output current to 4 A.

The overtemperature protection circuit is activated if the load current causes the junction temperature to exceed 125°C. When this occurs, the overtemperature protection circuitry disables the output until the junction temperature falls below approximately 110°C, at which point the output is reenabled. If the fault condition persists, the output cycles off and on until the fault is removed.

Additional protection is provided by an overcurrent limit that forces the device into a constant current mode of operation.

The ADP196-01 incorporates a quick output discharge (QOD) circuit to discharge the output capacitance when the ADP196-01 output is disabled.

ESD protection structures are shown in the block diagram as Zener diodes (see Figure 21).

The ADP196 is a low quiescent current device with a nominal 4 MΩ pull-down resistor on its enable pin (EN).

The ADP196 is available in a space-saving 1.0 mm × 1.5 mm, 0.5 mm pitch, 6-ball WLCSP and a tiny 2.0 mm × 2.0 mm × 0.55 mm, 0.65 mm pitch, 6-lead LFCSP.

APPLICATIONS INFORMATION

CAPACITOR SELECTION

Output Capacitor

The ADP196 is designed for operation with small, space-saving ceramic capacitors but functions with most commonly used capacitors when the effective series resistance (ESR) value is carefully considered. The ESR of the output capacitor affects the response to load transients. A typical 1 μF capacitor with an ESR of 0.1 Ω or less is recommended for good transient response. Using a larger value of output capacitance improves the transient response to large changes in load current.

Input Bypass Capacitor

Connecting at least 1 μF of capacitance from V_{IN} to GND reduces the circuit sensitivity to the PCB layout, especially when high source impedance or long input traces are encountered. When more than 1 μF of output capacitance is required, increase the input capacitance to match it.

GROUND CURRENT

The major source of ground current in the ADP196 is the internal charge pump for the FET drive circuitry. Figure 22 shows the typical ground current when $V_{EN} = V_{IN}$ and varies from 1.8 V to 5.5 V.

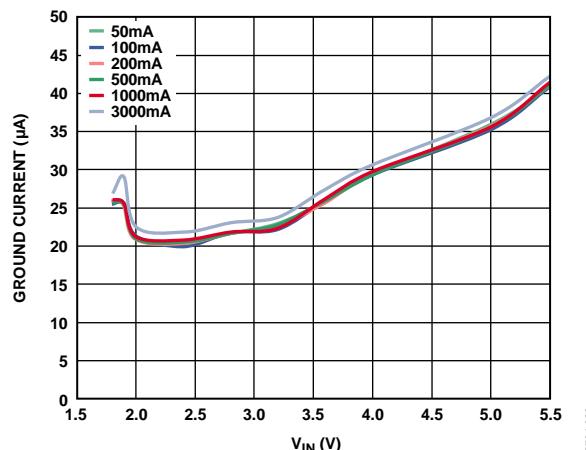
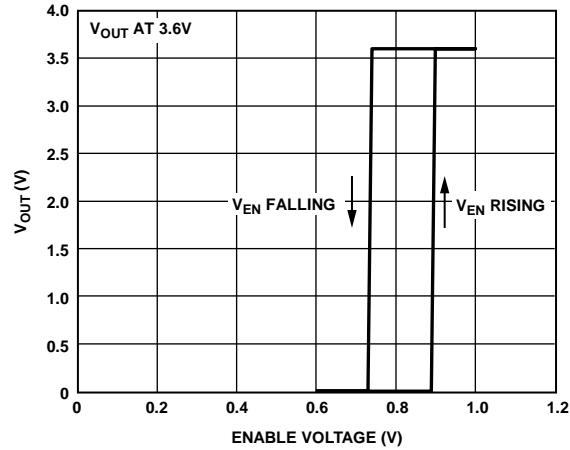


Figure 22. Ground Current vs. Input Voltage (V_{IN}) for Different Load Currents

ENABLE FEATURE

The ADP196 uses the EN pin to enable and disable the V_{OUT} pin under normal operating conditions. As shown in Figure 23, when a rising voltage (V_{EN}) on the EN pin crosses the active threshold, V_{OUT} turns on. When a falling voltage (V_{EN}) on the EN pin crosses the inactive threshold, V_{OUT} turns off.



10704-024

Figure 23. Typical EN Pin Operation

As shown in Figure 23, the EN pin has built-in hysteresis. The hysteresis prevents on/off oscillations that can occur due to noise on the EN pin as it passes through the threshold points.

The EN pin active/inactive thresholds are derived from the V_{IN} voltage; therefore, these thresholds vary with changing input voltage. Figure 24 shows the typical EN active/inactive thresholds when the input voltage varies from 1.8 V to 5.5 V.

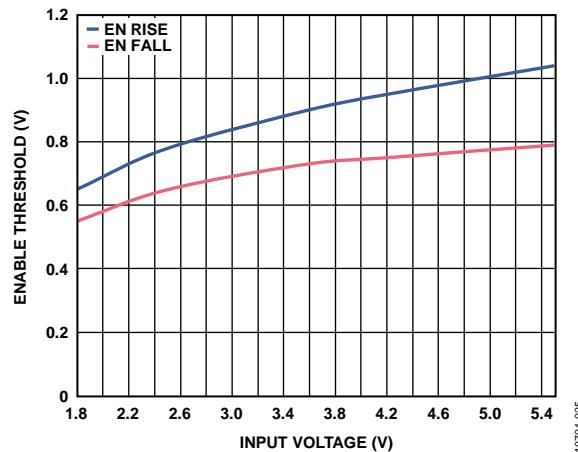


Figure 24. Typical EN Thresholds vs. Input Voltage (V_{IN})

TIMING

Turn-on delay is defined as the interval between the time that V_{EN} exceeds the rising threshold voltage and when V_{OUT} rises to ~10% of its final value. The ADP196 includes circuitry that has a typical 2 ms turn-on delay and a controlled rise time to limit the V_{IN} inrush current. As shown in Figure 25 and Figure 26, the turn-on delay is nearly independent of the input voltage.

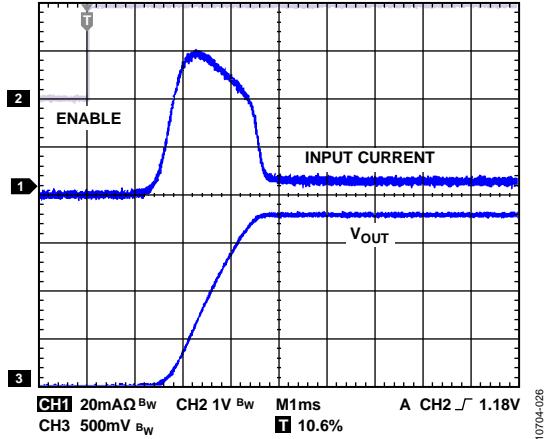


Figure 25. Typical Turn-On Time and Inrush Current, $V_{IN} = 1.8$ V, $C_{OUT} = 47 \mu\text{F}$, 330Ω Load

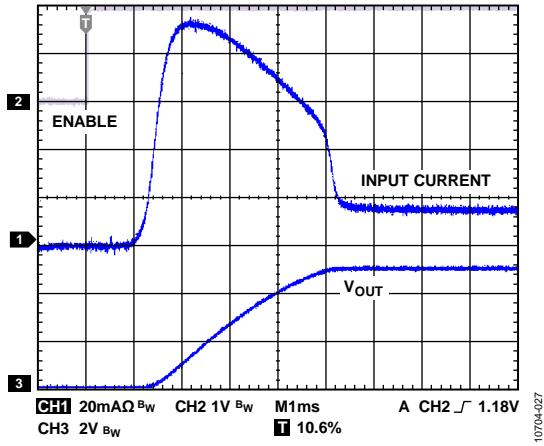


Figure 26. Typical Turn-On Time and Inrush Current, $V_{IN} = 5$ V, $C_{OUT} = 47 \mu\text{F}$, 330Ω Load

The rise time is defined as the time it takes the output voltage to rise from 10% to 90% of V_{OUT} reaching its final value. The rise time is dependent on the rise time of the internal charge pump.

For very large values of output capacitance, the RC time constant (where C is the load capacitance, C_{LOAD} , and R is the $R_{DSON} \parallel R_{LOAD}$) can become a factor in the rise time of the output voltage. Because R_{DSON} is much smaller than R_{LOAD} , an adequate approximation for RC is $R_{DSON} \times C_{LOAD}$. An input or load capacitor is not required for the ADP196; however, capacitors can be used to suppress noise on the board.

The turn-off time is defined as the time it takes for the output voltage to fall from 90% to 10% of V_{OUT} reaching its final value. The turn-off time is also dependent on the RC time constant of the output capacitance and load resistance. Figure 27 shows typical turn-off times with $V_{IN} = 1.8$ V to 5 V, $C_{OUT} = 47 \mu\text{F}$, and $R_{LOAD} = 330 \Omega$.

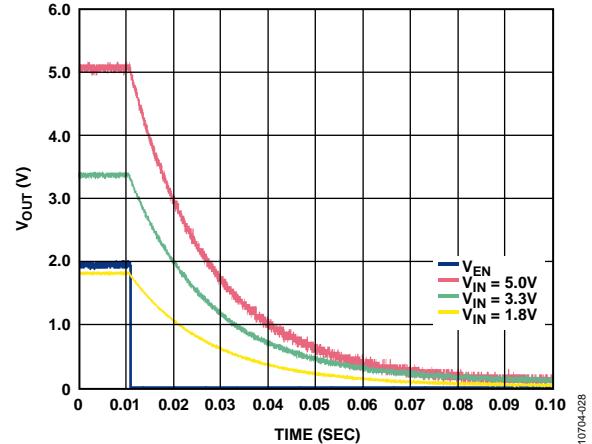


Figure 27. Typical Turn-Off Time

CURRENT-LIMIT AND THERMAL OVERLOAD PROTECTION

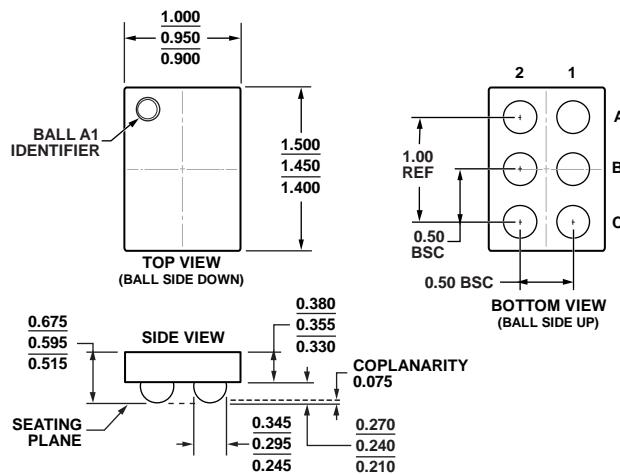
The ADP196 is protected against damage due to excessive power dissipation by current-limit and thermal overload protection circuits. The ADP196 is designed to limit current when the output load reaches 4 A (typical). When the output load exceeds 4 A, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 125°C (typical). Under extreme conditions (that is, high ambient temperature and/or high power dissipation) when the junction temperature starts to rise above 125°C, the output is turned off, reducing the output current to zero. When the junction temperature falls below 110°C, the output is turned on again, and the output current is restored to its operating value.

Consider the case where a hard short from VOUT to ground occurs. At first, the ADP196 current limits so that only 4 A is conducted into the short. If self-heating of the junction is great enough to cause its temperature to rise above 125°C, thermal shutdown is activated, turning off the output and reducing the output current to zero. As the junction temperature cools and falls below 110°C, the output turns on and conducts 4 A into the short, again causing the junction temperature to rise above 125°C. This thermal oscillation between 110°C and 125°C causes a current oscillation between 4 A and 0 mA that continues as long as the short remains at the output.

Current-limit and thermal overload protections are intended to protect the device against accidental overload conditions. For reliable operation, device power dissipation must be externally limited so that the junction temperature does not exceed 125°C.

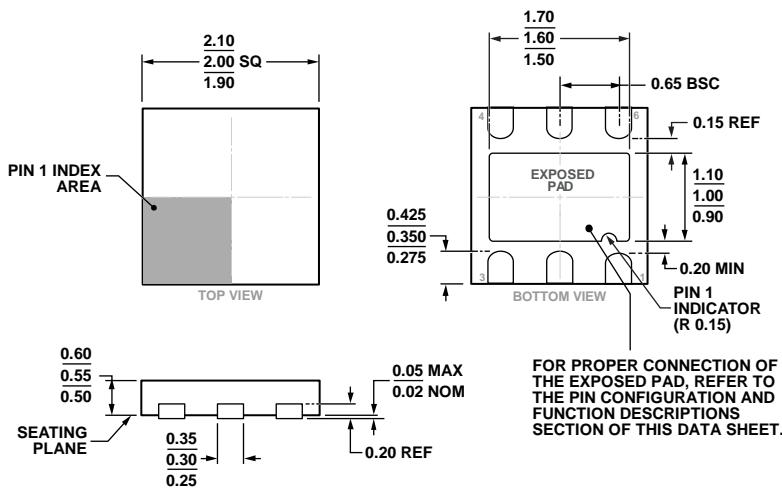
OUTLINE DIMENSIONS



11-08-2012-B

Figure 28. 6-Ball Wafer Level Chip Scale Package [WLCSP]
(CB-6-2)

Dimensions shown in millimeters



02-06-2013-B

Figure 29. 6-Lead Lead Frame Chip Scale Package [LFCSP_UD]
2.00 mm x 2.00 mm Body, Ultra Thin, Dual Lead
(CP-6-3)

Dimensions shown in millimeters

ORDERING GUIDE

| Model ¹ | Temperature Range | Package Description | Package Option | Branding |
|--------------------|-------------------|--|----------------|----------|
| ADP196ACBZ-R7 | -40°C to +85°C | 6-Ball Wafer Level Chip Scale Package [WLCSP] | CB-6-2 | AW |
| ADP196ACPZN-R7 | -40°C to +85°C | 6-Lead Lead Frame Chip Scale Package [LFCSP_UD] | CP-6-3 | AW |
| ADP196ACBZ-01-R7 | -40°C to +85°C | 6-Ball Wafer Level Chip Scale Package [WLCSP], Quick Output Discharge Option | CB-6-2 | BK |
| ADP196ACPZN-01-R7 | -40°C to +85°C | 6-Lead Lead Frame Chip Scale Package [LFCSP_UD], Quick Output Discharge Option | CP-6-3 | BK |
| ADP196CP-EVALZ | | Evaluation Board | | |

¹Z = RoHS Compliant Part.

Данный компонент на территории Российской Федерации**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибуторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ Р В 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru
moschip.ru_4

moschip.ru_6
moschip.ru_9